

WIDEBAND POWER AMPLIFIER MODULE, 0.5 - 15 GHz

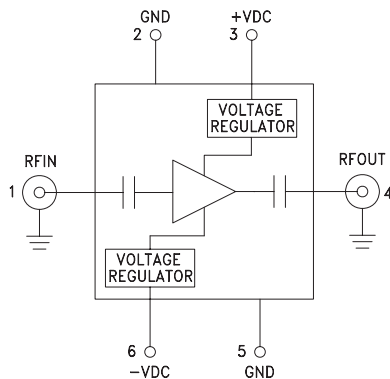


Typical Applications

The HMC-C036 Wideband PA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

- Gain: 12 dB
- P1dB Output Power: +28 dBm
- Regulated Supply and Bias Sequencing
- Hermetically Sealed Module
- Field Replaceable SMA connectors
- 0 to +85°C Operating Temperature

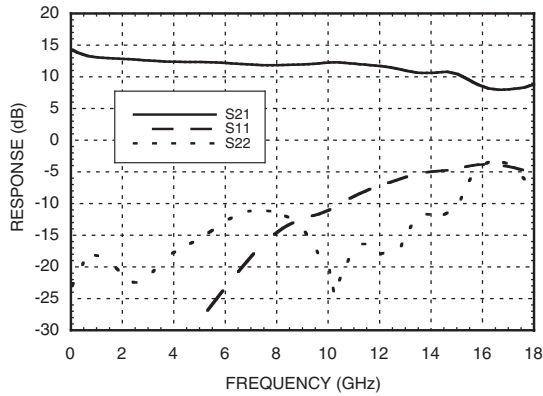
General Description

The HMC-C036 is a GaAs MMIC PHEMT Power Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 0.5 GHz and 15 GHz. The amplifier provides 12 dB of gain, up to +36 dBm output IP3 and up to +28 dBm of output power at 1 dB gain compression. Gain flatness is excellent from 2 - 12 GHz making the HMC-C036 ideal for EW, ECM RADAR, Fiber Optic and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are DC blocked. Integrated voltage regulators allow for flexible biasing of both the negative and positive supply pins, while internal bias sequencing circuitry assures robust operation.

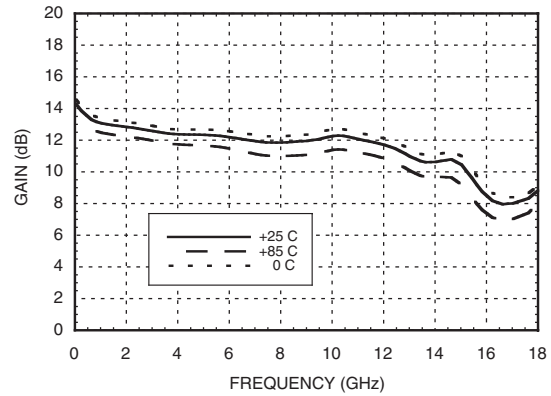
Electrical Specifications, $T_A = +25^\circ C$, +VDC = +11V to +16V, -VDC = -3V to -12V

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	0.5 - 6.0			6.0 - 12.0			12.0 - 15.0			GHz
Gain	9.5	12.5		9	12		8	11		dB
Gain Flatness		±0.3			±0.3			±0.6		dB
Gain Variation Over Temperature		0.02			0.02			0.02		dB/ °C
Noise Figure		4.5			4.5			7.0		dB
Input Return Loss		22			11			4		dB
Output Return Loss		13			12			10		dB
Output Power for 1 dB Compression (P1dB)	25	28		23	26		23	26		dBm
Saturated Output Power (Psat)		29			27			28		dBm
Output Third Order Intercept (IP3)		36			34			32		dBm
Positive Supply Current (+IDC)		360			360			360		mA
Negative Supply Current (-IDC)		-5.5			-5.5			-5.5		mA

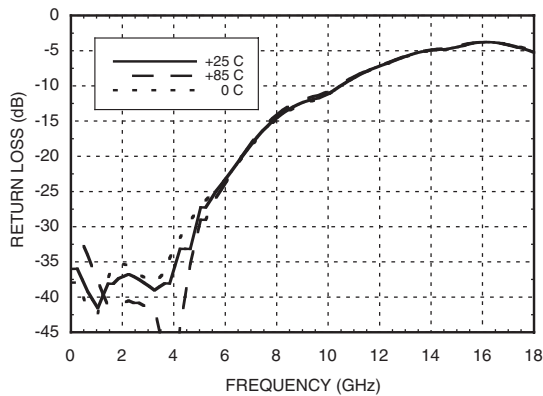
Gain & Return Loss



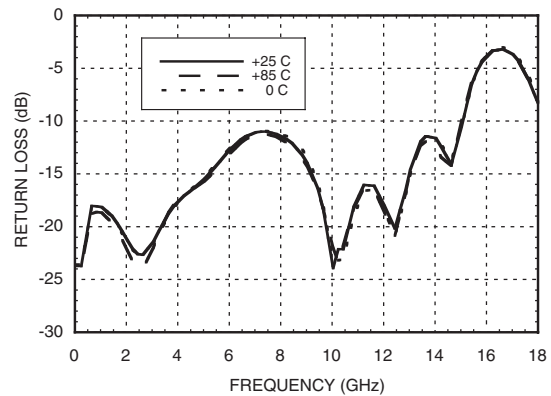
Gain vs. Temperature



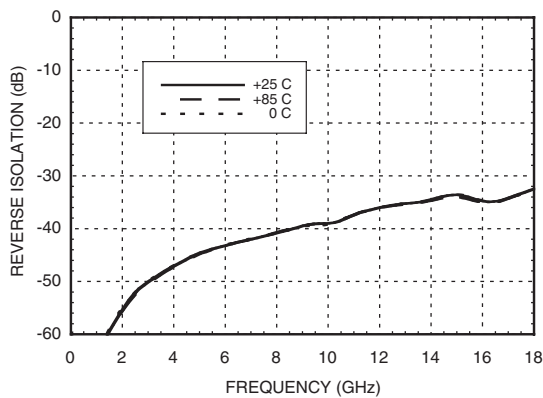
Input Return Loss vs. Temperature



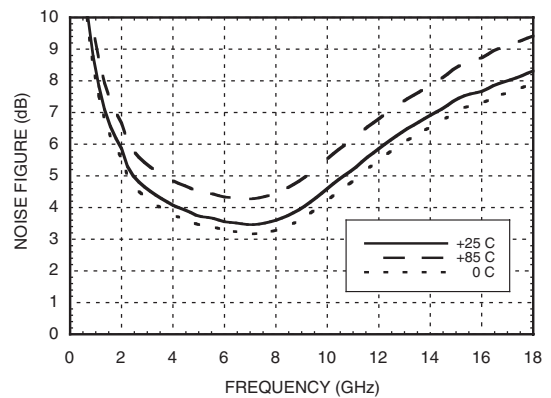
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature



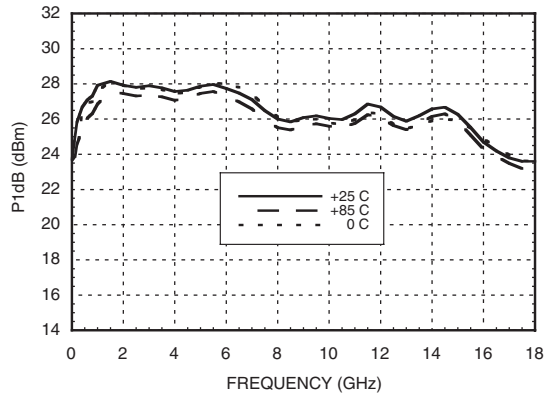
Noise Figure vs. Temperature



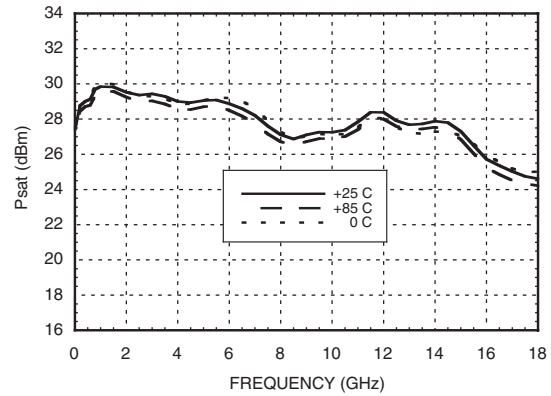
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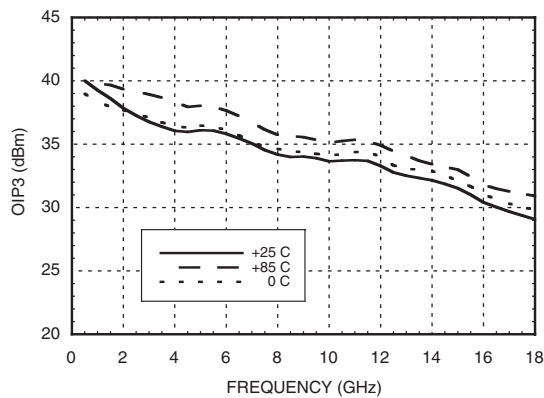
P1dB vs. Temperature



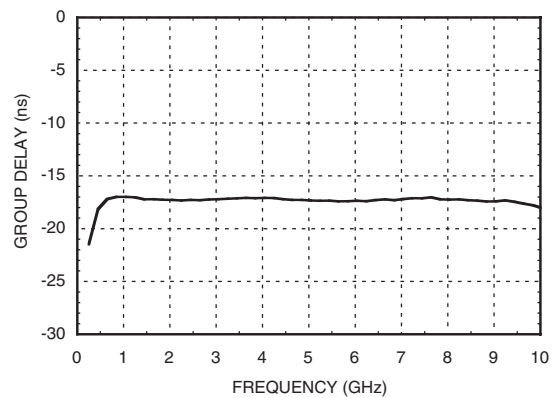
Psat vs. Temperature



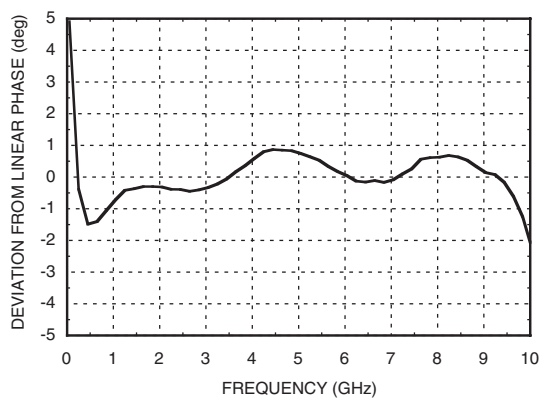
Output IP3 vs. Temperature



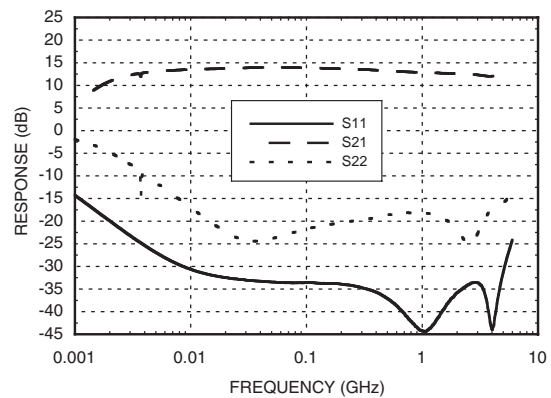
Group Delay



Deviation from Linear Phase



Low Frequency Gain & Return Loss





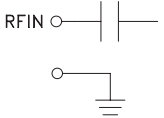

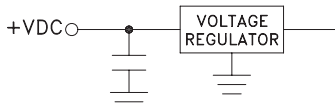
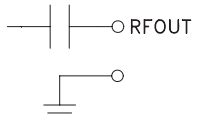
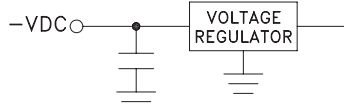
Absolute Maximum Ratings

Positive Bias Supply Voltage (+VDC)	+17V Max
Negative Bias Supply Voltage (-VDC)	-16V Min.
RF Input Power (RFin)	+30 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	0 to +85 °C



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms from 0.5 - 15 GHz.	
2, 5	GND	Power supply ground.	
3	+VDC	Positive power supply voltage for the amplifier.	
4	RFOUT & RF Ground	RF output connector, SMA female. This pin is AC coupled and matched to 50 Ohms from 0.5 - 15 GHz.	
6	-VDC	Negative power supply voltage for the amplifier	

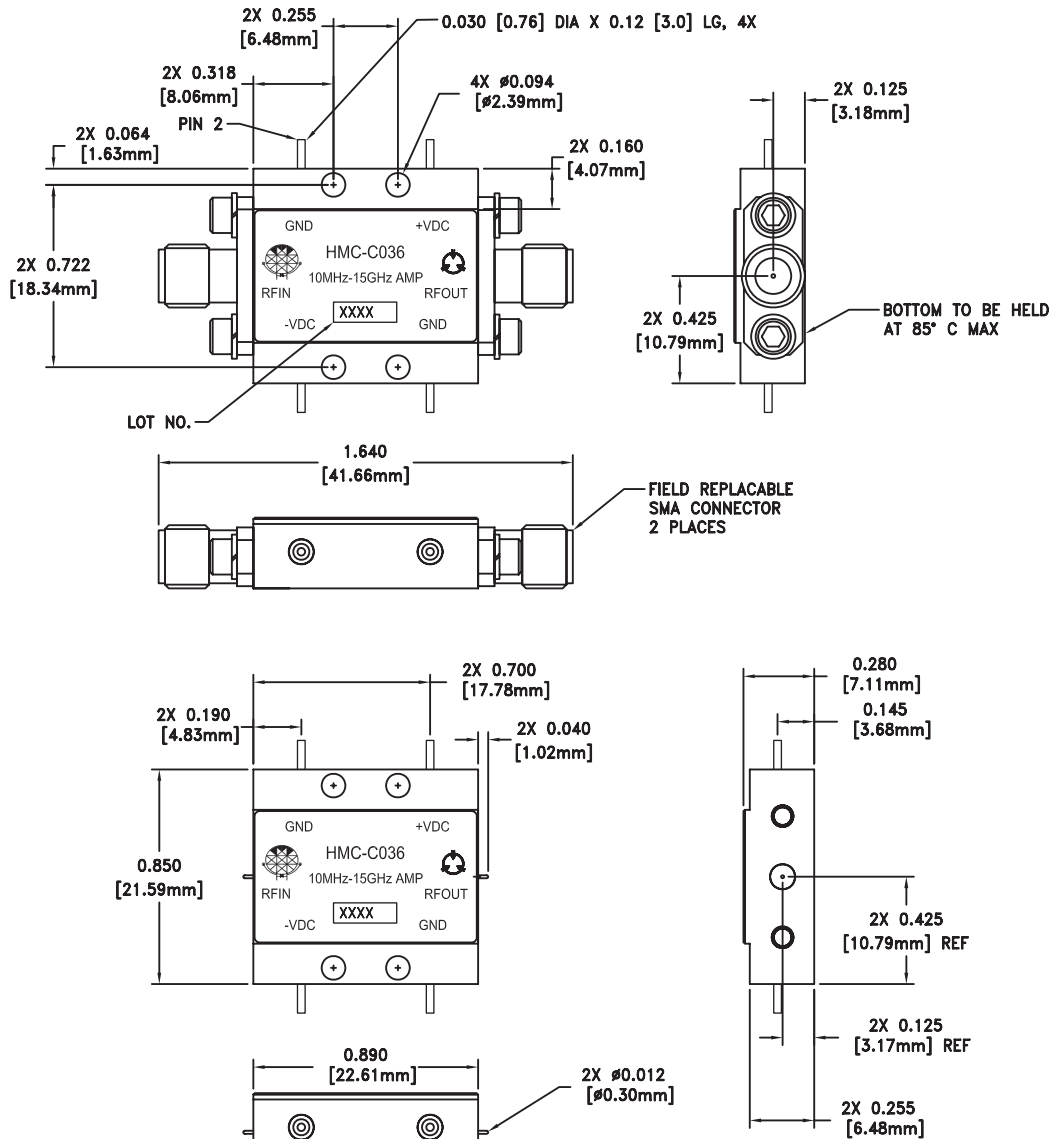
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AMPLIFIERS

Outline Drawing



Typical Package Weight

Package	23.1 gms
Spacer	N/A
+/- 1 gms Tolerance	

NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
2. SPACER MATERIAL: ALUMINUM
3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
5. TOLERANCES ±0.010 [0.25] UNLESS OTHERWISE SPECIFIED.
6. FIELD REPLACABLE SMA CONNECTORS. TENSOLITE 5602 - 5CCSF OR EQUIVALENT.



MICROWAVE CORPORATION v01.0407



HMC-C036

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Notes: